CMOS Digital Integrated Circuits Silicon Monolithic

74VHC00FT

1. Functional Description

• Quad 2-Input NAND Gate

2. General

The 74VHC00 is an advanced high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

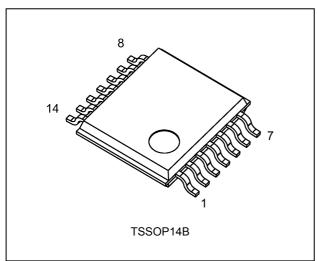
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

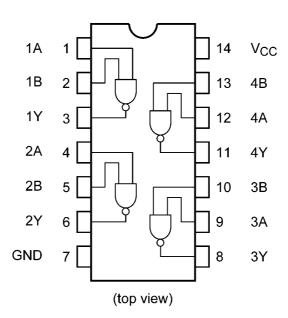
- (1) High speed: $t_{pd} = 3.7$ ns (typ.) at $V_{CC} = 5$ V
- (2) Low power dissipation: $I_{CC} = 2 \mu A (max)$ at $T_a = 25 \text{ °C}$
- (3) High noise immunity: $V_{\rm NIH} = V_{\rm NIL} = 28 \% V_{\rm CC}$ (min)
- (4) Power-down protection is provided on all inputs.
- (5) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (6) Wide operating voltage range: $V_{CC(opr)} = 2$ to 5.5 V
- (7) Low noise: $V_{OLP} = 0.8 V (max)$
- (8) Pin and function compatible with the 74 serise (74AC/HC/AHC/LV etc.) 00 type.

4. Packaging

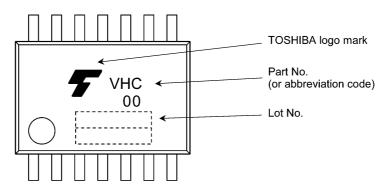


5. Pin Assignment

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6. Marking



7. IEC Logic Symbol

1A (1) 1B (2)	&	(<u>3)</u> 1Y
2A (4) 2B (5)		<u>(6)</u> 2Y
3A (9)		<u>(8)</u> 3Y
3B (10) 4A (12) 4B (13)		<u>(11)</u> 4Y
4D		

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8. Truth Table

А	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	-0.5 to 7.0	V
Input voltage	V _{IN}	-0.5 to 7.0	
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}	-20	mA
Output diode current	Ι _{ΟΚ}	±20	
Output current	I _{OUT}	±25	
V _{CC} /ground current	I _{CC}	±50	
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	C°

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	
Output voltage	V _{OUT}		0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 85	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V_{CC} = 5 ± 0.5 V	0 to 20	

Note: The operating ranges are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

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11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	_	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	—	
Low-level input voltage	V _{IL}	—		2.0	—	_	0.5	V
				3.0 to 5.5	—	-	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	2.0	—	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			I _{OH} = -4 mA	3.0	2.58		—	
			I _{OH} = -8 mA	4.5	3.94		—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			I _{OL} = 4 mA	3.0	—	_	0.36	
			I _{OL} = 8 mA	4.5		_	0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	_	±0.1	μA
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—		2.0	

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	—	V
				3.0 to 5.5	$V_{CC} imes 0.7$	—	
Low-level input voltage	VIL	—		2.0	_	0.50	V
				3.0 to 5.5	_	$V_{CC} imes 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	—	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -4 mA	3.0	2.48	_	
			I _{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	—	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5		20.0	

11.3. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		$\textbf{3.3}\pm\textbf{0.3}$	15	—	5.5	7.9	ns
				50	_	8.0	11.4	
			5.0 ± 0.5	15	_	3.7	5.5	
				50	—	5.2	7.5	
Input capacitance	C _{IN}				_	4	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)			_	19	_	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate)

11.4. AC Characteristics

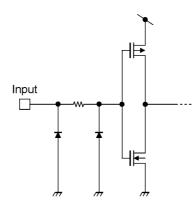
(Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	9.5	ns
			50	1.0	13.0	
		5.0 ± 0.5	15	1.0	6.5	
			50	1.0	8.5	
Input capacitance	C _{IN}			_	10	pF

11.5. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.3	-0.8	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		1.5	

11.6. Input Equivalent Circuit

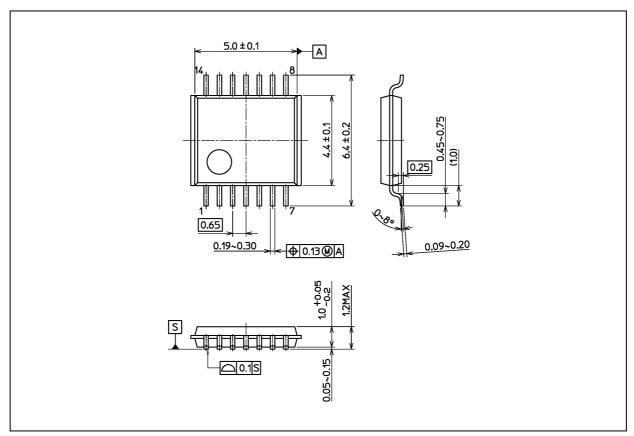




74VHC00FT

Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

Pa	ackage Name(s)
Nickname: TSSOP14B	

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